

Stability Investigation of Se- and Te-Substituted Tetrahedrite

Hailong Yang, Marie-Christine Record, Ziya Aliev, Pascal Boulet

▶ To cite this version:

Hailong Yang, Marie-Christine Record, Ziya Aliev, Pascal Boulet. Stability Investigation of Seand Te-Substituted Tetrahedrite. Journal of Electronic Materials, 2020, 49 (6), pp.3566-3576. 10.1007/s11664-020-08043-8 . hal-02507691

HAL Id: hal-02507691 https://hal.science/hal-02507691v1

Submitted on 10 Feb2022

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers. L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

1 Stability investigation of Se- and Te-substituted tetrahedrite

2 Hailong Yang ^{1,2}, Marie-Christine Record^{2,*}, Ziya Aliev³, Pascal Boulet¹

3 ¹ Aix-Marseille Univ., CNRS, MADIREL, Marseille, France

4 ²Aix-Marseille Univ., CNRS, IM2NP, Marseille, France

³Azerbaijan State Oil and Industry University, AZ1010 Baku, Azerbaijan

6 * corresponding author : m-c.record@univ-amu.fr

7

DFT (density functional theory) and QTAIM (quantum theory of atoms in molecules) 8 9 calculations have been performed to investigate the influence of Se and Te substitutions on 10 the stability of tetrahedrite. The formation energies, the laplacian of the electron density, the 11 total and local volume changes and the site charges ones have been determined. The DFT 12 results show that the single atom substitution is the most preferred one and that selenium is preferred for sulphur replacement whereas antimony can be equally replaced by selenium and 13 14 tellurium. However as selenium substitutes for either sulphur or antimony, QTAIM 15 calculations evidenced large structural and chemical changes in the strutures. Additional experimental results, in agreement with QTAIM ones, allow us to conclude that the 16 17 investigation of alloys stability can not be limited to DFT calculations of formation energies and total volume changes. QTAIM appears as a valuable complementary method to get 18 19 information on phase stabilities.

- 20 Key words: Cu-Sb-S system; substituted tetrahedrite; phase stability; DFT; QTAIM
- 21

22 INTRODUCTION

23 Copper antimony chalcogenides have high potentialities as semiconductors for electro-24 optic devices, thermoelectric devices, optical recording media and sustainable solar cell. As 25 examples we can mention Cu₃SbSe₃ which has enormously drawn attention of the researchers 26 in the thermoelectric field because of its ultra-low lattice thermal conductivity, and the Cu-Sb-27 S compounds that are modern state-of-the-art thermoelectric materials for midtemperature heat-to-power conversion with the advantage of being environmental friendly. The 28 29 thermoelectric figure of merit zT for many doped and natural tetrahedrite materials 30 (Cu₁₂Sb₄S₁₃) gets close to unity at 450°C; this value is comparable to that of conventional p-31 type TE materials. However because of the complexity of the Cu-Sb-S phase diagram around 32 the Cu₁₂Sb₄S₁₃ composition, these materials are always constituted of several phases for 33 which the proportions generally differ from a sample to another one. The large scale use of 34 tetrahedrite for thermoelectric applications necessitates the mastering of the properties and 35 thus the mastering of the material constitution. A way could be to extend the composition 36 range of the tetrahedrite stability. To reach this goal, we investigated the stability of various 37 substituted tetrahedrites in which S atoms were replaced by Se and/or Te ones. This work was 38 mainly carried out by coupled DFT and QTAIM calculations and complemented by some 39 experiments.

40

41 THE Cu-Sb-S SYSTEM

Information on the constitutive binary systems Sb-S, Cu-S and Cu-Sb can be found in Ref. 1-6, Ref. 7-8 and Ref. 9-11, respectively. The Sb-S phase diagram only shows one condensed stable binary phase Sb₂S₃ (stibnite) with a congruent melting and two regions of liquid immiscibility. The Cu-S binary system contains three intermediate phases, namely Cu₂S (chalcocite), Cu₉S₅ (digenite) and CuS (covellite) and a solid solution between digenite and chalcocite extending from 83 to 1129°C. Numerous phases have also been identified at low temperatures (<103°C) but considerable uncertainties still remain both on the stability range of the digenite and on the temperatures of phase transitions in the low temperature range. Moreover no studies on the stability of the new minerals as roxbyite (Cu_{1.78}S), geerite (Cu_{1.6}S) and spionkopite (Cu_{1.4}S) have been performed. There are several intermediate phases in the Cu-rich region but only two (δ and η) exist at room temperature.

53 Phase stability and phase relations in the Cu-Sb-S ternary system have been studied by numerous authors.^{3,12-19} There are four compounds in the Cu-Sb-S ternary system, namely 54 55 CuSbS₂ (chalcostibite), Cu₃SbS₃ (skinnerite), Cu₃SbS₄ (famatinite), and Cu₁₂Sb₄S₁₃ 56 (tetrahedrite). Chalcostibite, CuSbS₂, forms readily by reaction from the elements and did not show any composition range.³ By contrast, Golovei *et al.*²⁰ found a homogeneity range for 57 CuSbS₂ and a polymorphic transformation. Skinnerite was first reported by Godolikov et al.¹⁷ 58 59 who prepared it by sintering Cu₂S and Sb₂S₃ at 480°C and 530°C. It has the ideal composition 60 of Cu₃SbS₃ with a small composition field along the line Cu₂S-Sb₂S₃ at 500°C. Karup-Møller et al.²¹ have found these ore aggregates crystallized at about 400°C from metal-rich residual 61 62 magmatic fluids markedly deficient in sulfur. Cu₃SbS₃ is stable in the Cu-Sb-S system in the 63 temperature range 359-607°C. Below 359°C this phase decomposes into a mixture of native antimony, chalcostibite and tetrahedrite,³ but if it is cooled slowly, it decomposes to give a 64 mixture of tetrahedrite, antimony and digenite.²² At 607°C, Cu₃SbS₃ congruently melts. 65 Pfitzner²³ have investigated both the high and low-temperature phases. The high-temperature 66 67 modification is disordered and stable above 122°C, and is supposed to show high copper ion conductivity or at least a high copper diffusion coefficient. The low-temperature form is 68 ordered and stable below -9°C. Famatinite, Cu₃SbS₄, derived from sphalerite, melts 69 70 congruently at 627°C, and is not known to have any stable polymorph forms.³ The only 71 compound with an extensive composition field in the Cu-Sb-S system is tetrahedrite. The

basic structure of minerals of the tetrahedrite group was solved by Pauling and Newman²⁴ and 72 73 now the widely accepted formula Cu₁₂Sb₄S₁₃ represented its composition. As for the Pauling 74 and Neuman formula, $Cu_{12+x}Sb_{4+y}S_{13}$, where $0 \le x \le 1.92$ and $-0.02 \le y \le 0.27$, there is no clear evidence so far proving the substitution schemes implied in this formula are correct.²⁴ Cambi 75 and Elli¹⁴ have given an extreme composition range for tetrahedrites going from 4Cu₂S·Sb₂S₃ 76 to 3Cu₂S·Sb₂S₃ (i.e. Cu₈Sb₂S₇ to Cu₃SbS₃). Since Skinner *et al.*³ have not managed to prepare 77 a single homogenous phase with the composition $Cu_{12}Sb_4S_{13}$, they believed that this phase has 78 79 a stability temperature range below 300°C. These authors also found that the unit cell edges of tetrahedrite decrease with the sulfur content. Tatsuka and Morimoto²⁵ reported the 80 81 formation of pseudo-tetrahedrite (T'₃) which is stable between 250 and 350°C and is a 82 superlattice of $Cu_{12+x}Sb_{4+y}S_{13}$ (T₃) (lattice parameter of T'₃ is twice that of T₃). Along the Cu₂S-Sb₂S₃ section reported by Chang *et al.*,²⁶ the composition of pseudo-tetrahedrite ranges 83 from Cu₃SbS₃ to Cu_{12,39}Sb_{4,54}S₁₃. Below 250°C, a prolonged annealing of T₃ or T'₃ results in 84 a phase mixture consisting of Cu₃SbS₄, Cu_{2-x}S and Sb. Makowicky and Skinner²⁷ have 85 86 confirmed that tetrahedrite has two room-temperature phases Cu-poor phase Cu_{12.3}Sb₄S₁₃ and 87 Cu-rich phase Cu_{13.8}Sb₄S₁₃ produced by a low-temperature exsolution of tetrahedrite 88 Cu_{12.59}Sb_{4.03}S₁₃. However when melts, whose compositions lie near that of tetrahedrite, are 89 cooled at the rate of 50-100°C/h, instead of separation of the phase Cu₃SbS₃, metastable solid 90 tetrahedrite solutions crystallize out and then decompose to phases with a complex structure, which are absent in the phase diagram.²⁸ The crystal structure of stoichiometric tetrahedrite 91 $Cu_{12}Sb_4S_{13}$ was determined for the first time by Skinner *et al.*³ There is no phase transitions 92 for Cu12Sb4S13 up to 300°C, and the two exsolution phases Cu12.3Sb4S13 and Cu13.8Sb4S13 93 94 show a high copper-ion mobility even at room temperature. According to [29] tetrahedrite is 95 stable from $4Cu_2S \cdot Sb_2S_3$ to Cu_3SbS_3 at 300°C and from $4Cu_2S \cdot Sb_2S_3$ to $Cu_{12}Sb_4S_{13}$ at 400°C. Whereas Skinner et al.³ reported above 500°C a rapid shrinkage of the composition range for 96

- 97 tetrahedrite followed by its decomposition into Cu₃Sb₁S₄, Cu₃SbS₃ and Cu_xS (x going from
- 98 1.6 to 2) at 543°C, Il'yasheva²⁸ evidenced an incongruent melting for this phase at $574\pm2^{\circ}$ C.
- All the ternary phases are stable at 500°C.
- 100 The crystallographic data and the thermodynamic properties of the ternary solid101 phases are given in Table 1 and Table 2, respectively.
- 102

Table I. Crystallographic data of the Cu-Sb-S ternary solid phases							
Crystal	Space	Lattice parameters (pm)	Reference				
system	group						
Tetragonal	I-42m	a=538.5,c=1075.4	[30]				
Orthorhombic	Pnma	a=601.8,b=379.58,c=1449.5	[32]				
Cubic	I-43m	a=1032.4	[32]				
Monoclinic	$P2_1/c$	a=781.5,b=1025.2,c=1327.0	[33]				
	Crystal system Tetragonal Orthorhombic Cubic Monoclinic	graphic data of the Cu-Sb-S tCrystalSpacesystemgroupTetragonalI-42mOrthorhombicPnmaCubicI-43mMonoclinicP21/c	graphic data of the Cu-Sb-S ternary solid phasesCrystalSpaceLattice parameters (pm)systemgroupTetragonalI-42mI-42ma=538.5,c=1075.4OrthorhombicPnmaa=601.8,b=379.58,c=1449.5CubicI-43ma=1032.4MonoclinicP21/ca=781.5,b=1025.2,c=1327.0				

Phase	Temperature	$\Delta_{\rm f} G^0$	$\Delta_{ m f} { m H}^0$	S^0
		(J/mol of atoms)	(J/mol of atoms)	(J/K.mol of atoms)
Cu ₃ SbS ₄	25°C	-207500 ± 3900	-200000 ± 6300	298 ± 18
CuSbS ₂	25°C	-121400 ± 3400	-119000 ± 3500	148 ± 6.4
Cu ₃ SbS ₃	25°C	-197800 ± 3800	-189300 ± 6500	269.5 ± 13.7

105 SUBSTITUTED TETRAHEDRITE: COMPUTATIONAL PART

106 Computational details

The calculations have been performed in the frame of the density-functional theory^{35,36} 107 108 using the gradient-corrected Perdew-Burke-Ernzerhof (PBE) exchange-correlation functionals.³⁷ All the structures have been relaxed to their equilibrium state and the energy 109 and force thresholds have been fixed to 10⁻⁷ Ry and 10⁻⁴ Ry.bohr⁻¹, respectively. The projector 110 111 augmented wave (PAW) method³⁸ has been used to treat nucleus and core and valence electrons interactions with cutoffs 48 Ry for the energy and 480 Ry for the density. A 4x4x4 112 113 k-point mesh has been utilized. The Quantum Espresso program package has been used for these calculations.³⁹ 114

The analysis of the bonding structure of the alloys has been performed using Bader's
 quantum theory of atoms in molecule⁴⁰ as implemented in the Critic2 program.⁴¹

117

118 Crystalline description of the tetrahedrite

119 The tetrahedrite crystal structure with stoichiometric formula Cu₁₂Sb₄S₁₃ is composed 120 of two formula units and belongs to the body-centered cubic Bravais lattice with group number 217 (I-43m). It contains 29 atoms in the irreducible lattice located at five 121 122 crystallographic sites. Copper atoms are in the two distinct Wyckoff positions (WP) 12e and 12d. Cu 12e is at the centre of a triangle formed by three sulphur atoms (two S in 24g WP and 123 124 one S in 2a WP) and the assembly constitutes a trigonal plane. If one includes two antimony 125 atoms on either sides of the plane the assembly is a trigonal bipyramid (Fig. 1a). It is noted 126 that the Cu-Sb bond distance of this trigonal bipyramid is rather large with 3.536 Å and the 127 Cu-S ones amount to 2.246 Å and 2.250 Å. It has been reported that, the weak bonding 128 between Cu and Sb leads to soft vibrational modes of Cu having large anisotropic thermal motion, which could explain the low thermal conductivity of the tetrahedrite.^{32,42} Six Cu 129









a) Copper 12e at the centre of a trigonal bipyramid with S 2a, S 24g and Sb 8c at the apex.

b) Sulphur 2*a* at the centre of the lattice and at the center of an octahedron formed by six Cu *12e*.



c) Copper 12d arranged in square at the lattice face. They are located at the centre of a tetrahedron with S 24g at the apex.



d) Sulphur 24g in the centre of a distorted tetrahedron formed by two Cu 12d (at the lattice face), one Cu 12e (at the lattice edge) and one Sb 8c.



e) Antimony at the apex of a tetrahedron formed with three sulphur 24g atoms

- 148 Fig. 1: Structural features of the tetrahedrite. a) Environment of copper in 12e Wyckoff
- 149 position (WP); b) Environment of sulphur in 2a WP; c) Environment of copper in 12d WP; d)
- 150 Environment of sulphur in 24g WP; e) Environment of antimony in 8c WP.

152 **Procedure**

153 The substituting elements considered in this work are Se and Te. The substituted 154 atoms have been chosen as S and Sb ; S as a chalcogen and Sb since its replacement by Te has 155 been evidenced in natural tetrahedrite.⁴³ As neither Cu₁₂Sb₄Se₁₃ nor Cu₁₂Sb₄Te₁₃ have been reported in literature, in order to preclude a too big distorsion of the cell only the substitutions by one and two atoms per cell have been examined. The investigated compositions are the following ones : $Cu_{12}Sb_4S_{12.5}Se_{0.5}$, $Cu_{12}Sb_4S_{12}Se_1$,

159 Cu12Sb3.5Se0.5S13, Cu12Sb3Se1S13, Cu12Sb4S12.5Te0.5, Cu12Sb4S12Te1, Cu12Sb3.5Te0.5S13, 160 Cu₁₂Sb₃Te₁S₁₃. The atom replacements on all the crystallographic sites (2a and 24g for S, 8c 161 for Sb) have been envisaged. For 2 Te or Se atoms substitutions in the case of sulphur, three 162 possible situations have been considered: 2 atoms at site S 24g, one atom at site S 24g and the 163 other at site S 2a, and 2 atoms at site S 2a. For 2 Te or Se atoms substitutions in the case of 164 antimony, since in pure tetrahedrite the eight antimony atoms form a somewhat distorted cube 165 (hereafter called pseudo-cube) inside the cubic lattice, three possibilities have been 166 considered: two atoms along the pseudo-cube edge, two atoms along the face diagonal of the 167 pseudo-cube and 2 atoms along the principal diagonal of the pseudo-cube. The stability of the 168 phases have been investigated by determining both the formation energies of the alloys using 169 DFT calculations and the total and local volume changes using QTAIM ones.

170 The formation energies have been determined from the energies E calculated by DFT171 according to the following formula:

172
$$\Delta E_f = \frac{E(Cu_x Sb_y S_z X_t) - xE(Cu) - yE(Sb) - zE(S) - tE(X)}{x + y + z + t}$$
(1)

173 Recalling that the number of formula in the unit cell of tetrahedrite is 2, a one-atom sulphur 174 and antimony substituted tetrahedrite on the one hand and a two-atoms sulphur and antimony 175 substituted tetrahedrite on the other hand correspond to $Cu_{12}Sb_4S_{12.5}X_{0.5}$, $Cu_{12}Sb_{3.5}X_{0.5}S_{13}$, and 176 $Cu_{12}Sb_4S_{12}X$, $Cu_{12}Sb_3XS_{13}$, respectively.

- 177
- 178
- 179

181 **Results**

182 *Formation energies and total lattice volume changes*

183 Substitutions of Se and Te for S. The calculated values are given in Table 3. For a 184 single substitution, both selenium and tellurium atoms prefer occupying site 24g, the 185 formation energies being -160.7 and -151.6 meV/atom respectively. The substitution at site 186 2a is much less favourable by about 8 meV/atom. This preference for the 24g site has already been experimentally evidenced for Se by Lu et al.⁴⁴ For two Te or Se atoms substitutions as 187 188 mentioned above three possible situations have been envisaged: two atoms at site S 24g, one 189 atom at site S 24g and the other at site S 2a, and 2 atoms at site S 2a. For the two former 190 possibilities we observe that for a given substituting atom the energies are very close and 191 actually lie in the error bar that we estimate to be 3-4 meV/atom. The 2-atoms substitution at 192 site 2a is the least preferential one for both Se and Te. We note that, the substitution with 193 selenium is more preferred than that with tellurium, as the formation reactions pertaining to 194 Se are more exothermic than those pertaining to Te.

These results show that whatever the substituting atom (Se or Te), the most favorable situation corresponds to a single atom substitution at site 24g and that irrespective of the considered site, the replacement of S by Se is the most favorable one.

Table III: Formation energies (in meV/atom) and total volume change of the cell (in bohr³) for 1 and 2 atoms Te or Se substitutions for sulphur. Columns 1 and 8 correspond to the ranking w.r.t. formation energies.

	Te substituted for S	$\Delta E_{\rm f}$	ΔV	$\Delta E_{\rm f}$	ΔV	Se substituted for S	
1	1 Te for S <i>24g</i>	-151.6	+1.297	-160.7	+0.093	1 Se for S <i>24g</i>	1
2	1 Te for S <i>2a</i>	-144.0	+2.452	-153.1	+0.312	1 Se for S <i>2a</i>	4
3	2 Te for 2 S <i>24g</i>	-136.7	+3.066	-155.5	+0.943	2 Se for 2 S <i>24g</i>	2
4	1 Te for S 24g and	-136.2	+3.976	-153.5	+0.685	1 Se for S <i>24g</i> and	3
	1 Te for S 2a					1 Se for S <i>2a</i>	
5	2 Te for 2 S 2a	-127.3	+6.200	-144.7	+1.828	2 Se for 2 S <i>2a</i>	5

200 The total volume of the substituted structures changes sizeably with respect to that of 201 pristine tetrahedrite as can be seen in Table 3. We observe that, except for 2-Se-atoms substitution, the more energetically favorable the site is, the smaller the volume change. In 202 203 agreement with the respective atomic volumes of Se and Te atoms, sites substituted with Te 204 are likely to be more affected, as we observe a larger total volume change, than when Se is the 205 substituting element. It appears that, substitutions on site S 2a induces more drastic changes in 206 the total volume than those on site S 24g, the volume change being about two to three times 207 as large. As a consequence, the volume increase for 2-atoms substitution at site S 2a is as large as +6 and nearly +2 Bohr³ for Te and Se, respectively. These results on the volumes are 208 209 in line with the energetic ones as they can lead to the same inferences as above.

211 Substitutions of Se and Te for Sb. The calculated values are given in Table 4. 212 Remarkably enough, the formation energies are quite similar, suggesting therefore that both 213 Se and Te may equally substitute for Sb. The most preferred substitution is by far obtained 214 with one Se or Te atom only in place of antimony. The energy difference between the one-215 atom and two-atoms substitutions is above 20 meV/atom for both Se and Te, the largest 216 energy difference being 23 meV/atom for Se. For two-atoms substitutions, the three 217 configurations, namely two atoms along the pseudo-cube edge, two atoms along the face 218 diagonal of the pseudo-cube and two atoms along the principal diagonal of the pseudo-cube, 219 are energetically undistinguishable since the differences in formation energies lie in the error 220 bar (3-4 meV/atom); they spread in the ranges [-122.2; -123.8] meV/atom and [-120.4; -221 122.5] meV/atom for Te and Se, respectively.

222 Regarding the total volume change of the lattice upon substitutions, it is remarkable 223 that they are all negative irrespective of the substituting atom and configurations. The smallest 224 volume change corresponds to the one-atom substitution. For two-atoms substitutions the 225 situation is contrasted between Se and Te. For Se, the volume changes remain rather small 226 (less than 2 Bohr³). For Te, the two-atoms substitutions at the edge of the pseudo-cube still 227 lead to the modest volume change of -2.6 Bohr³. By contrast, a huge change is observed 228 when two Sb atoms are replaced by Te on the pseudo-cube face and body diagonals. 229 Notwithstanding this observation, the structures are not energetically destabilized as 230 mentioned above.

	Te substituted for Sb	$\Delta E_{\rm f}$	ΔV	$\Delta E_{\rm f}$	ΔV	Se substituted for Sb	
1	1 Te for Sb <i>8c</i>	-144.8	-1.2	-143.4	-1.24	1 Se for Sb <i>8c</i>	1
2	2 Te for 2 Sb 8 <i>c</i> (pseudo-cube edge)	-123.8	-2.6	-122.5	-1.91	2 Se for 2 Sb <i>8c</i> (pseudo-cube edge)	2
3	2 Te for 2 Sb 8 <i>c</i> (pseudo-cube diagonal)	-123.6	-26.5	-120.7	-1.71	2 Se for 2 Sb <i>8c</i> (pseudo-cube diagonal)	3
4	2 Te for 2 Sb <i>8c</i> (pseudo-cube face diagonal)	-122.2	-36.1	-120.4	-1.93	2 Se for 2 Sb 8c (pseudo-cube face diagonal)	4

Table IV: Formation energies (in meV/atom) and total volume change of the cell (in bohr³) for 1 and 2 atoms Te or Se substitutions for antimony. Columns 1 and 8 correspond to the ranking w.r.t. formation energies.

Partial conclusions. From the formation energies viewpoint the most favourable situation corresponds to a single atom substitution, both Te and Se preferring replacing sulphur at the 24g Wyckoff position to sulphur 2a and antimony 8c ones. Selenium is preferred for the sulphur substitution whereas tellurium and selenium are equally likely to replace antimony.

The lattice volume change is positive when substitutions occur at the sulphur sites, whereas it is negative at the antimony ones, the one atom substitution leading in all cases to the lower volume variation. For two-atoms substitutions, irrespective to the substituted element and site, Te leads to higher volume changes than Se. One can note that, whereas these volume variations are extremely large when Te substitutes for Sb, the energetic variations are quite small.

244

246 Local volume and atomic charge changes and electron density laplacian

In order to get better insight into the influence of substitutional atoms in the tetrahedrite, the atomic site volume and charge changes and electron density laplacian have been calculated using Bader's theory of atoms in molecules. Only one-atom substitutions are considered here since these lead to the structures bearing highest formation energies and smallest volume changes.

Pure tetrahedrite. The electron density laplacian of pure tetrahedrite in the (110) plane is depicted in figure 2. This plane contains S 2a atoms (e.g. sulphur located at abscissa ca. 22), which are bonded to two copper 12e (at abscissa ca. 20 and 24); the four remaining copper 12e atoms that complete the octahedra around sulphur ones are located in two planes rotated by 45° from the (110) one and are thus not visible.

In the (110) plane, one can see that in agreement with the structure description already reported in literature, Cu *12e* is bonded to two S *24g* atoms and despite the long distance between copper *12e* and antimony atoms (3.536 Å, see above), these atoms are chemically bonded to each other since a bond path is found to connect them and a bond critical point (BCP) is found at the atomic basins boundary. Indeed, in the Bader's description the bonds are characterized by a path connecting two atoms, with b (see Fig. 2) depicting the position of the BCP where the electron density gradient vanishes.



Fig. 2: Electron density laplacian of pure tetrahedrite. Legend. b: bond critical point; r: ring
critical point; c: cage critical point. Color legend: electron accumulation in blue; electron
depletion in green.

269

270 Substitutions of Se and Te for S 24g. As one selenium atom replaces a sulphur 24g 271 atom, one of the Cu_{12e}-Sb bonds gets broken. This effect is observable as one compares Fig. 2 272 (at x=26) and Fig. 3a (at x=31). Important distortions in the structure are also observed, 273 probably to accommodate the large size of Se: the Cu_{12e}-Se bond distance (2.541 Å) increases 274 by 13% compared to the Cu_{12e}-S one; Cu *12e* moves out of the trigonal plane by about 20%; 275 the angle Cu_{12e}-S_{2a}-Cu_{12e} of the octahedron height is 150° instead of 180°. One of the Cu_{12e}-276 Sb distances shortens by 20% (2.832 Å) while the other enlarges by 10% (3.896 Å) that leads 277 to the bond breaking.



a) Se substitution for S 24g

b) Te substitution for S 24g

Fig. 3: Electron density laplacian of substituted tetrahedrite. a) Se substitution for S 24g; b)
Te substitution for S 24g. Legend. b: bond critical point; r: ring critical point; c: cage critical
point. Color legend: electron accumulation in blue; electron depletion in green.

Table V: Variation of the atomic charge (in electron charge unit) and atomic sites volume (in bohr³) upon Se substitution for S *24g*.

	24g (S)	2a (S)	12e (Cu)	12d (Cu)	8c (Sb)
Δq	+0.01	+0.05	-0.01	-0.01	0
ΔV	+1.15	+5	-2.26	+0.45	-1.31

283

The effect of this replacement on the atomic charges and atomic volumes can be seen in Table 5. Interestingly, sulphur 2a is the most affected atom with a positive change of both properties; a volume increase as large as +5 bohr³ is observed. The Cu *12e* atom to which Se is bonded is also affected, though in a lower extent and in the opposite way with a decrease of both the volume and the charge. The site of the antimony atom to which Se is bonded 289 undergoes a volume decrease although its charge remains unchanged. The volume decrease is 290 about the same in absolute value as the volume increase of the S 24g site where the 291 substitution occurs.

292 As Te substitutes for sulphur 24g the same overall trends are observed as for Se. The 293 graph of the electron density laplacian (Fig. 3b) shows that one of the Cu_{12e}-Sb is broken 294 (3.592 Å, +1.2%) while the other one is strengthened (3.181 Å, -10%) and the octahedron 295 around S 2a is distorted (the Cu-S-Cu angle is 163°). However, we note that these structural 296 changes are less drastic than for Se, although the Te substitution is energetically less 297 favorable than the Se one. The volume change of the site 24g of sulphur, where the Te 298 substitution occurs, increases sizably (Table 6) by +3.3 Bohr³ (2.9 times that for Se 299 substitution) and the volume of the site 12d (Cu) is almost twice as large as that for the Se 300 substitution. Only the site 12e of Cu undergoes a volume decrease of about the same amount 301 as for Se substitution. These local volume changes explain why the overall volume of the 302 structure increases (Table 3) as Te substitutes for sulphur.

303 We note finally that the atomic site charges vary in the same way and same extent as 304 for the Se substitution.

305

Table VI: Variation of the atomic charge (in electron charge unit) and atomic sites volume (in bohr ³) upon Te substitution for S $24g$						
	24g (S)	2a (S)	12e (Cu)	12d (Cu)	8c (Sb)	
Δq	+0.01	+0.04	-0.01	-0.01	-0.01	

-2.1

306

 ΔV

+3.3

307 Substitutions of Se and Te for Sb. The influence of the Se and Te substitutions for 308 Sb on the electron density laplacian and bonding network of the tetrahedrite is depicted in 309 figure 4a and 4b, respectively. Interestingly, as Se substitutes Sb a new chemical bond

+5.6

+0.2

+0.7

310 appears between the selenium atom and the sulphur one of the 2a site in spite of the large 311 interatomic distance (4.027 Å); The bond is characterized by a bond path between both atoms 312 and a bond critical point located *ca*. x=24 (Figure 4a). The Se-S_{2a} interatomic distance is 313 1.156 Å shorter than the Sb-S_{2a} one of the pure tetrahedrite. The appearance of this new bond 314 implies a distortion of the octahedron around the S_{2a} atom; the Cu-S-Cu angle amounts to 153.07° and the sulphur atom moves out of the Cu₄ plane by 17.9° in the direction of Se. As 315 316 to the case of the Te for Sb substitution, the bonding network of the structure is not affected 317 compared to that of the pure tetrahedrite (Figure 4b). Some differences in the atomic charge 318 and volume changes between these two types of substitutions can be observed (Tables 7 and 319 8). First, the atomic charges are barely varying upon Te substitution. By contrast, S_{2a} and Sb 320 undergo significant increase and decrease, respectively, of their charge upon Se substitution, 321 which can be correlated to the appearance of the new bond between these atoms.

322 The volumes are affected in various ways. For both Se and Te substitutions, the 323 volume of S_{2a} increases drastically by up to 5 and 7 Bohr³, respectively, and that of Cu_{12e} 324 (bonded to S_{2a}) decreases by 2.5 Bohr³, on average. The Cu_{12d} atoms being far from the 325 substitution site, their volumes are not affected. As to the substituted site Sb, the volume 326 decreases (increases) drastically (slightly) when Se (Te) is the substituting atom, these 327 variations being in line with the differences in atomic sizes between Sb, Se and Te. Since the 328 substitution at the Sb site is energetically equally plausible by Se and Te, we can infer that the 329 total contributions to the formation energy of the various structural, electronic and bonding 330 changes occuring in the structures are comparable.

- 331
- 332
- 333
- 334



a) Se substitution for Sb δc b) Te substitution for Sb δc

Fig. 4: Electron density laplacian of substituted tetrahedrite. a) Se substitution for Sb *8c*; b)
Te substitution for Sb *8c*. Legend. b: bond critical point; r: ring critical point; c: cage critical
point. Color legend: electron accumulation in blue; electron depletion in green.

Table VII: Variation of the atomic charge (in electron charge unit) and atomic sitesvolume (in bohr³) upon Se substitution for Sb 8c.

		24g (S)	2a (S)	12e (Cu)	12d (Cu)	8c (Sb)
	Δq	+0.03	+0.05	-0.01	0	-0.06
	ΔV	-0.90	+5.1	-2.32	0	-4.07
339						
340						
341						
342						
343						

	24g (S)	2a (S)	12e (Cu)	12d (Cu)	8c (Sb)
Δq	+0.01	+0.01	0	+0.01	-0.02
ΔV	+0.60	+7.2	-2.7	-0.2	+0.6

Table VIII: Variation of the atomic charge (in electron charge unit) and atomic sites volume (in bohr³) upon Te substitution for Sb *8c*.

Partial conclusions. Irrespective of both the substituting and the substituted atoms, the atomic charge changes are quite weak on all sites, the maximum being 0.06 electron charge unit. When substitution occurs on the S_{24g} site, irrespective of the substituting atom, charge change is only noticeable on the S_{2a} site. When substitution occurs on the Sb_{8c} site, the largest charge change occurs on this site while being weaker as Te substitutes for Sb.

Regarding the local volume changes, the S_{2a} site is the most impacted by both S_{24g} and Sb replacements. In all cases, the volume of the site S_{2a} increases. One can see that the volume of the site Cu_{12e} , which is adjacent to the site S_{2a} , decreases, though to a lesser extent. As one could expect, the impact of the substitution on the local volume changes is weaker when the site of interest is far from the substituted one (e.g. volume of the Cu_{12d} site when the replacement is on the Sb site).

The electron density laplacian shows few or even no chemical and structural modifications when Te substitutes for S_{24g} or Sb, respectively. In the case of Se, bigger structural distortions have been evidenced with the breaking of a Cu_{12e}-Sb bond when the substitution occurs on S_{24g} site and the formation of a Se- S_{2a} one when the substitution occurs on Sb site.

361

363 SUBSTITUTED TETRAHEDRITE: EXPERIMENTAL PART

364 DFT calculations of formation energies and total volume changes showed that : i) the 365 most favourable situation corresponds to a single atom substitution, ii) selenium is preferred 366 for the sulphur substitution whereas tellurium and selenium are equally likely to replace 367 antimony, whereas QTAIM calculations evidenced larger structural and chemical distortions 368 when Se is the substituting element irrespective of the substituted site. Since these results 369 experimentally investigated the following seem inconsistent, we compositions: 370 Cu12Sb3.5Se0.5S13, Cu12Sb4S12.5Te0.5 and Cu12Sb3.5Se0.5S12.5Te0.5. We have not investigated Cu₁₂Sb_{3.5}Te_{0.5}S₁₃ and Cu₁₂Sb₄S_{12.5}Se_{0.5} as these works were already done by Bouyrie et al.⁴⁵ 371 372 and Lu et al.⁴⁴, respectively, and the authors found single-phased materials with a tetrahedrite 373 structure.

374

375 Synthesis and characterization

376 The three aforementioned ternary and quaternary alloys have been prepared by mixing 377 378 ²Pa) sealed silica ampoules. The mixture was heated up to 680 °C and maintained at this 379 temperature for 8 h. In order to get the equilibrium state, the samples have been quenched 380 from melt in cold water and annealed at 400°C for about 150 h. The constitutive phases of the 381 samples were evidenced by X-ray powder diffraction using a Bruker D8 Advance 382 diffractometer with Cu-K radiation in the 2θ range from 5° to 80° and their proportion were 383 evaluated by Rietveld refinement.

384

385

386

388 **Results**

The X-ray diffraction patterns for the three investigated samples are given in Figure 5 and the constitution of the alloys with the percentage of each phase determined by Rietveld refinement are given in Table 9.

392 When one Te atom is substituted for a S one, the alloy is constituted of one phase only 393 which crystallizes in a tetrahedrite structure. As expected the lattice parameter of this phase (a 394 = 1036.1 pm) is larger than that of the pure sulphur tetrahedrite (a=1032.4 pm, see above). 395 When one Se atom is substituted for a Sb one, the alloy is constituted of two phases in an 396 equivalent ratio. One of these phases crystallizes in a tetrahedrite structure with a lattice 397 parameter a= 1034.3 pm, the other one crystallizes in a famatinite structure with the lattice 398 parameters a=539.0 pm and c=1076.1 pm which are larger than those of the pure sulphur 399 famatinite (a=538.5 pm and c=1075.4 pm, see above). When one Se atom is substituted for a 400 Sb one and one Te is substituted for a S one, the alloy is mainly constituted (95%) of a 401 tetrahedrite phase, the secondary phase (5%) crystallizing in a famatinite structure.

The whole results show that in spite of low formation energies and high volume changes, alloys containing a tellurium atom at a sulphur site stabilize the tetrahedrite structure. This statement is in agreement with the QTAIM calculations, which find lower structural and chemical distortions when Te is the substituting element.



407 Fig. 5: X-ray diffraction patterns of $Cu_{12}Sb_4S_{12.5}Te_{0.5}$, $Cu_{12}Sb_{3.5}Se_{0.5}S_{13}$ and 408 $Cu_{12}Sb_{3.5}Se_{0.5}S_{12.5}Te_{0.5}$ alloys

Table IX: Constitution of the Cu12Sb4S12.5Te0.5, Cu12Sb3.5Se0.5S13 andCu12Sb3.5Se0.5S12.5Te0.5 samples and percentage of each phase determined by X-Raydiffraction measurements and Rietveld refinement.

Sample composition	Sample constitution (%)		
	Tetraedrite	Famatinite	
$Cu_{12}Sb_4S_{12.5}Te_{0.5}$	100	0	
$Cu_{12}Sb_{3.5}Se_{0.5}S_{13}$	45	55	
$Cu_{12}Sb_{3.5}Se_{0.5}S_{12.5}Te_{0.5}$	95	5	

410

411 CONCLUSION

In this work, we investigated Se and Te substitutions in tetrahedrite by coupling DFT and QTAIM calculations. DFT calculations of formation energies and total volume changes showed that the most favourable situation corresponds to a single atom substitution and that 415 selenium is preferred for the sulphur substitution whereas tellurium and selenium are equally 416 likely to replace antimony. By contrast, QTAIM calculations evidenced irrespective of the 417 substituted site, larger structural and chemical distortions when Se is the substituting element. 418 In order to clarify these inconsistencies, we experimentally investigated three alloys and 419 found that by contrast to a Se substitution for Sb, a Te susbtitution for S stabilizes the 420 tetrahedrite structure. This investigation shows that a DFT calculation of formation energies 421 and total volume changes is not sufficient to put forward conclusions on alloys stability. By 422 giving chemical and structural information on a compound, in addition of being a good 423 method to explain the structure-properties relationships, QTAIM appears as a valuable 424 method to get information on phase stabilities.

425

426 ACKNOWLEDGEMENTS

This work is financially supported by China Scholarship Council (CSC N°201608530165). This work was granted access to the HPC resources of the Centre Informatique National de l'Enseignement Supérieur (CINES), Montpellier, France under allocation A0050806881 made by the Grand Equipement National de Calcul Intensif (GENCI). It was also granted access to the HPC resources of Aix-Marseille Université financed by the project Equip@Meso (ANR-10-EQPX-29-01) of the program "Investissements d'Avenir" supervised by the Agence Nationale de la Recherche.

434

435 **REFERENCES**

- 436 1. E. H. Roseboom, An investigation of the system Cu-S and some natural copper
 437 sulfides between 25 ° and 700 °C, *Econ. Geol.* 61, 641-672 (1966).
- 438 2. P.B. Barton, The Fe-Sb-S system, *Econ. Geol.* 66, 121-132 (1971).

- 439 3. B. J. Skinner, F. D. Luce, E. Makovicky, Studies of the sulfosalts of copper III. Phases 440 and phase relations in the system Cu-Sb-S, Econ. Geol. 67, 924-938 (1972). 441 P.B. Barton Jr., Solid solutions in system Cu-Fe-S. Part I: The Cu-S and CuFe-S joins, 4. 442 Econ. Geol. 68, 455-465 (1973). 443 M. E. Fleet, Phase Equilibria at High Temperatures, Rev. Mineral. Geochem. 61, 365-5. 419 (2006). 444 445 F. Tesfaye Firdu, P. Taskinen, Thermodynamics and Phase Equilibria in the (Ni, Cu, 6. 446 Zn)-(As, Sb, Bi)-S Systems at Elevated Temperatures (300–900°C), Aalto University 447 Publications in Materials Science and Engineering (2010). 448 7. S. Maske, B.J. Skinner, Studies of the sulfosalts of copper: I, Phases and phase 449 relations in the system Cu-As-S, Econ. Geol. 66, 901-918 (1971).
- 450 8]. R.W. Potter, An electrochemical investigation of the system copper-sulfur, *Econ.*451 *Geol.* 72, 1524-142 (1977).
- 452 9. R.P. Elliot, Constitution of Binary Alloys 1st supplement, McGraw-Hill. New York453 (1965).
- 454 10. M. Hansen, K. Anderko, Constitution of binary alloys. McGraw-Hill (1965).
- 455 11. T.B. Massalski, Cu–Sb (copper–antimony). In: Binary alloy phase diagrams, vol 2,
 456 2nd edn. The Materials Information Society, Materials Park (1990).
- 457 12. V.F. Ross, The formation of intermediate sulfide phases in the solid state, *Econ. Geol.*458 49, 734-752 (1954).
- 459 13. J.H. Wernick, K.E. Benson, New semiconducting ternary compounds, *J. Phys. Chem.*460 Solids 3, 157-159 (1957).
- 461 14. L. Cambi, M. Elli, Processi Idrotermali-sintesi di solfosali da ossidi di metalli e
 462 metalloidi 2 Cuprosolfoantimoniti, *Chimica & Industria* 47, 136-147 (1965).

- 463 15. R.A. Kuliev, A.N. Krestovnikov, V.M. Glazov, Phase Equilibrium and Intermolecular
 464 Interactions in Systems Formed by Copper and Antimony Chalcogenides, *Russ. J.*465 *Phys. Chem. (Engl. Transl.)* 43, 1721-1723 (1969).
- 466 16. R.A. Kuliev, A.N. Krestovnikov, V.M. Glazov, Phase equilibria between copper and
 467 antimony chalcogenides, *Izvest Akad Nauk Sssr Neorg Materialy* 5, 2217-2218 (1969).
- 468 17. A.A. Godovikov, Bismuth Sulfosalts : their chemical composition, synthesis and
 469 classification. In Pecularities of the chemical composition, synthesis, classification,
 470 *Nauka*, Moscow, Russia (1972).
- 471 18. N.A. Il'yasheva, Investigation of the system Cu₂S-Sb₂S₃ at 320-400°C, *Neorg. Mater.*472 9, 1677-1679 (1973).
- L.T. Bryndzia, A. M. Davis, Liquidus phase relations on the quasi-binary join Cu₂SSb₂S₃: Implications for the formation of tetrahedrite and skinnerite , *Amer. Mineral.*74, 236-242 (1989).
- 476 20. M.I. Golovei, V.I. Tkachenko, M.Yu. Rigan, N.P. Stasyuk, Phase diagram of the
 477 system Cu₂S-Sb₂S₃ in the region of existence of CuSbS₂", *Neorg. Mater.* 26, 48-50
 478 (1990).
- 479 21. S. Karup-Møller, E. Makovicky, Skinnerite Cu₃SbS₃, a new sulfosalt from the
 480 Ilimaussaq alkaline intrusion, South Greenland, *Amer. Mineral* 59, 889-895 (1974).
- 481 22. H. J. Whitfield, Polymorphism in skinnerite Cu₃SbS₃, *Solid State Commun.* 33, 747482 748 (1980).
- 483 23. A. Pfitzner, Disorder of Cu⁺ in Cu₃SbS₃:structural investigations of the high- and low484 temperature modification, *Z. Kristallogr.* 213, 228-236 (1998).
- 485 24. L. Pauling, E.W. Neuman, The crystal structure of binnite, (Cu, Fe)₁₂As₄S₁₃, and the
 486 chemical composition and structure of minerals of the tetrahedrite group, *Z.*487 *Kristallogr.* 88, 54-62 (1934).

- 488 25. K. Tatsuka, N. Morimoto, Tetrahedrite stability relations in the Cu-Sb-S system, *Econ*.
 489 *Geol.* 72, 258-270 (1977).
- 490 26. Y.A. Chang, J.P. Neumann, U.V. Choudary, Phase Diagrams and Thermodynamic
 491 Properties of Ternary Copper-Sulfur-Metal Systems, *Incra Monograph VII, The*492 *Metallurgy of Copper* (1979).
- 493 27. E. Makovicky, B.J. Skinner, Studies of the sulfosalts of copper VII. Crystal structures 494 of the exsolution products $Cu_{12.3}Sb_4S_{13}$ and $Cu_{13.8}Sb_4S_{13}$ of unsubstituted synthetic 495 tetrahedrite, *Can. Mineral.* 17, 619-634 (1979).
- 496 28. N.A. Il'yasheva, Peculiarities of tetrahedrite crystallization in the system Cu-Sb-S,
 497 *Neorg. Mater.* 20, 563-657 (1984).
- T.-T. Chen, Compositional and thermal study on natural and synthetic phases in the
 system Ag₂S-Cu₂S-Sb₂S₃-Bi₂S₃, Degree of doctor, Cornell University (1971)
- J. Garin, E. Parthé, The crystal structure of Cu₃PSe₄ and other ternary normal
 tetrahedral structure compounds with composition 13564, *Acta Cryst. B* 28, 3672-3674
 (1972).
- A. Kyono, M. Kimata, Crystal structures of chalcostibite (CuSbS₂) and emplectite
 (CuBiS₂): Structural relationship of stereochemical activity between chalcostibite and
 emplectite, *Am. Mineral.* 90, 162-165 (2005).
- 506 32. B. J. Wuensch, The crystal structure of tetrahedrite, Cu₁₂Sb₄S₁₃, *Z. Kristallogr.* 119,
 507 437-453 (1964).
- 508 33. T. Balic Zunic, E. Makovicky, Determination of the crystal sructures of TiPbSbS₃,
 509 (Ti,K)Fe₃(SO₄)₂(OH)₆ and Cu₃SbS₃ from X-ray powder diffraction data, *Mat. Sci.*510 *Forum* 166-169, 659-664 (1994).

- M. Babanly, Y. Yusibov, N. Babanly, The EMF Method with Solid State Electrolyte
 in the Thermodynamic Investigation of Ternary Copper and Silver Chalcogenides,
 Electromotive Force and Measurement in Several Systems, Publisher InTech (2011).
- 514 35. P. Hohenberg; W. Kohn, Inhomogeneous electron gas, *Phys. Rev.* 136, B864-B871
 515 (1964).
- 516 36. W. Kohn, L.J. Sham, Self-Consistent Equations Including Exchange and Correlation
 517 Effects, *Phys. Rev.* 140, A1133-A1138 (1965).
- 518 37. J.P. Perdew, K. Burke, M. Ernzerhof, Generalized Gradient Approximation Made
 519 Simple, *Phys. Rev. Lett.* 77, 3865-3868 (1996).
- 520 38. P. E. Blöchl, *Phys. Rev. B* 50, 17953 (1994).
- 521 39. P. Giannozzi, S. Baroni, N. Bonini, et al., Quantum Espresso : a modular and open522 source software project for quantum simulations of materials, *J. Phys.: Condens.*523 *Matter* 21, 395502 (2009).
- 524 40. R.F.W. Bader, Atoms in Molecules A Quantum Theory, Oxford University Press,
 525 Oxford, (1990).
- 526 41. A. Otero-de-la-Roza, E. R. Johnson, V. Luaña, *Comput. Phys. Commun.* 185, 1007527 1018 (2014).
- 528 42. W. Lai, Y. Wang, D.T. Morelli, X. Lu, Adv. Funct. Mater. 25, 3648-3657 (2015).
- 529 43. X. Lu, D.T. Morelli, Y. Xia, F. Zhou, V. Ozolins, H. Chi, X. Zhou, C. Uher, High
 530 Supperformance Thermoelectricity in Earth-Abundant Compounds Based on Natural
 531 Supperformance Tetrahedrites, *Adv. Energy Mater.* 3, 342-348 (2013).
- 532 44. X. Lu, D. T. Morelli, Y.Wang, W. Lai, Y. Xia, V. Ozolins, Phase Stability, Crystal
 533 Structure, and Thermoelectric Properties of Cu₁₂Sb₄S_{13-x}Se_x Solid Solutions, *Chem.*534 *Mater.* 28, 1781–1786 (2016).

45. Y. Bouyrie, C. Candolfi, V. Ohorodniichuk, B. Malaman, A. Dauscher, J. Tobola, B.
Lenoir, Crystal structure, electronic band structure and high-temperature
thermoelectric properties of Te-substituted tetrahedrites Cu₁₂Sb_{4-x}Te_xS₁₃ (0.5≤x≤2.0), *J. Mater. Chem. C* 3, 10476-10487 (2015).